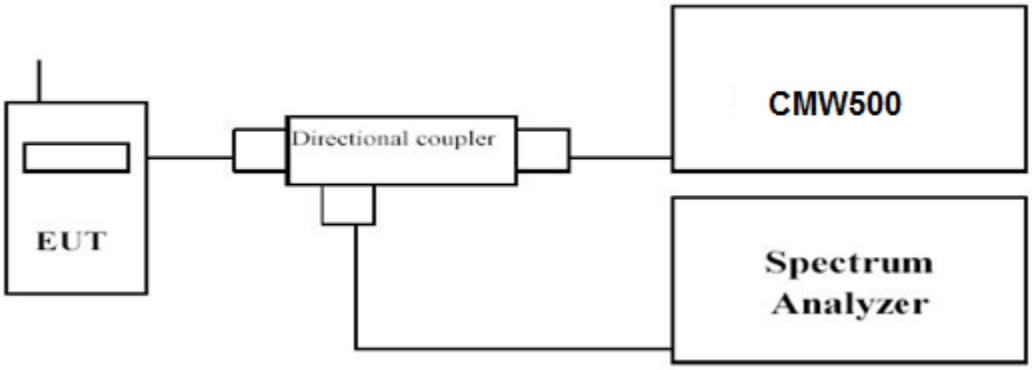
4.5 Spurious Emission

LIMIT

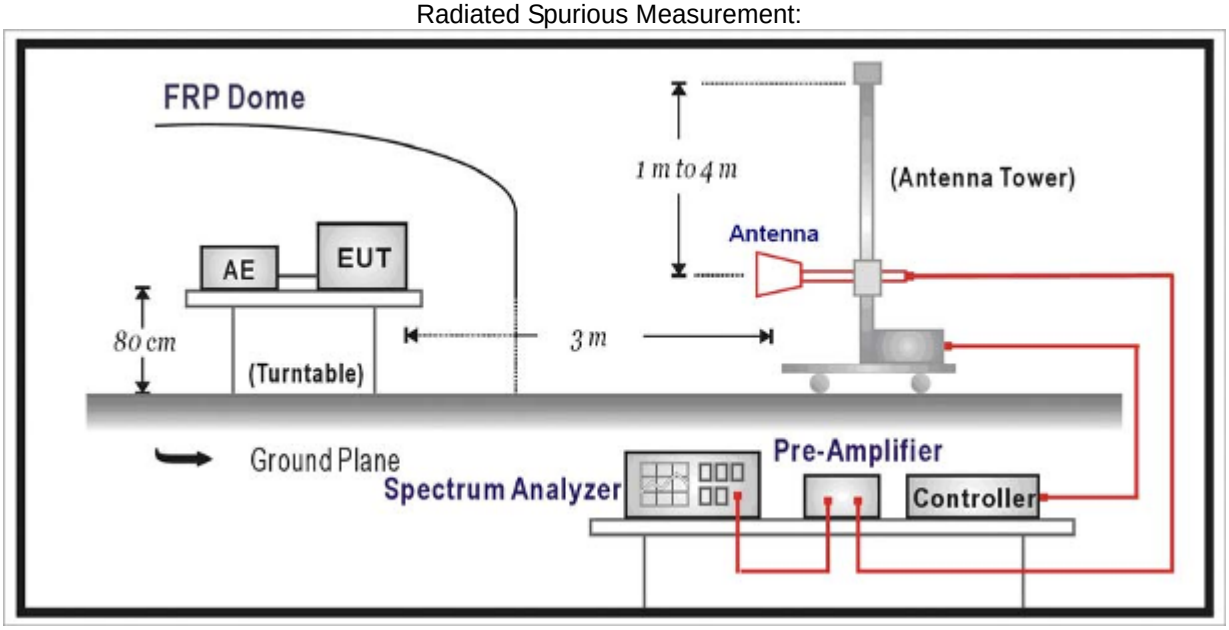
Per FCC §24.238, the power of any emission outside of the authorized operating frequency ranges must be attenuated below the transmitting power (P) by a factor of at least 43 + 10log(P) dB.

TEST CONFIGURATION

Conducted Spurious Measurement:



Radiated Spurious Measurement:



TEST PROCEDURE

The EUT was setup according to EIA/TIA 603E

Conducted Spurious Measurement:

a. Place the EUT on a bench and set it in transmitting mode.
b. Connect a low loss RF cable from the antenna port to a spectrum analyzer and CMW500 by a Directional Couple.
c. EUT Communicate with CMW500 then selects a channel for testing.
d. Add a correction factor to the display of spectrum, and then test.
e. The resolution bandwidth of the spectrum analyzer was set sufficient scans were taken to show the out of band Emission if any up to10th harmonic.

Radiated Spurious Measurement:

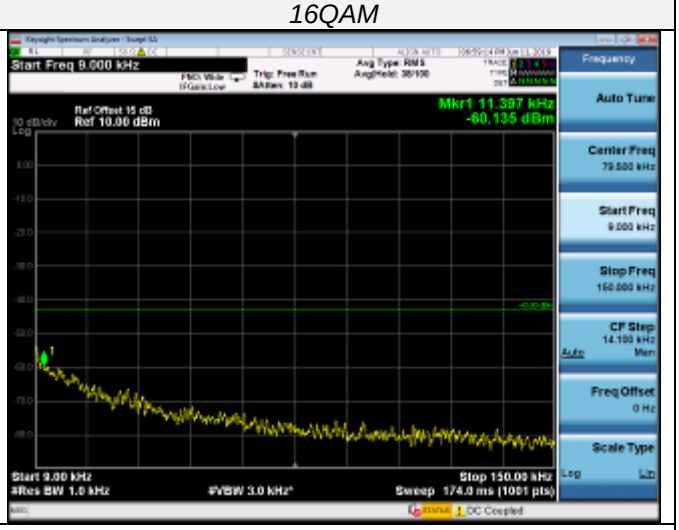
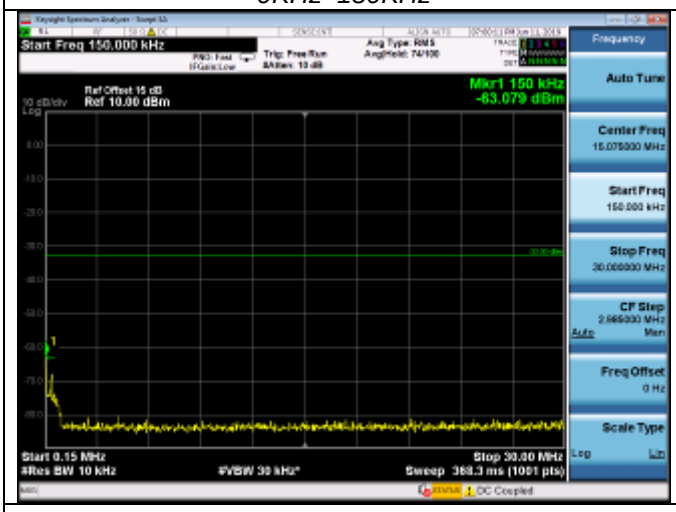
a. The EUT shall be placed at the specified height on a support, and in the position closest to normal use as declared by provider.
b. The test antenna shall be oriented initially for vertical polarization and shall be chosen to correspond to the frequency of the transmitter
c. The output of the test antenna shall be connected to the measuring receiver.
d. The transmitter shall be switched on and the measuring receiver shall be tuned to the frequency of the transmitter under test.
e. The test antenna shall be raised and lowered through the specified range of height until a maximum signal level is detected by the measuring receiver.
f. The transmitter shall then be rotated through 360°in the horizontal plane, until the maximum signal level is detected by the measuring receiver.
g. The test antenna shall be raised and lowered again through the specified range of height until a maximum signal level is detected by the measuring receiver.
h. The maximum signal level detected by the measuring receiver shall be noted.
i. The transmitter shall be replaced by a substitution antenna.
j. The substitution antenna shall be orientated for vertical polarization and the length of the substitution antenna shall be adjusted to correspond to the frequency of the transmitter.
k. The substitution antenna shall be connected to a calibrated signal generator.
l. If necessary, the input attenuator setting of the measuring receiver shall be adjusted in order to increase the sensitivity of the measuring receiver.
m. The test antenna shall be raised and lowered through the specified range of height to ensure that the maximum signal is received.
n. The input signal to the substitution antenna shall be adjusted to the level that produces a level detected by the measuring receiver, that is equal to the level noted while the transmitter radiated power was measured, corrected for the change of input attenuator setting of the measuring receiver.
o. The measurement shall be repeated with the test antenna and the substitution antenna orientated for horizontal polarization.
p. The measure of the effective radiated power is the larger of the two levels recorded at the input to the substitution antenna, corrected for gain of the substitution antenna if necessary.
q. The resolution bandwidth of the spectrum analyzer was set at 100 kHz for Part 22 and 1MHz for Part 24. The frequency range was checked up to 10th harmonic.
r. Test site anechoic chamber refer to ANSI C63.

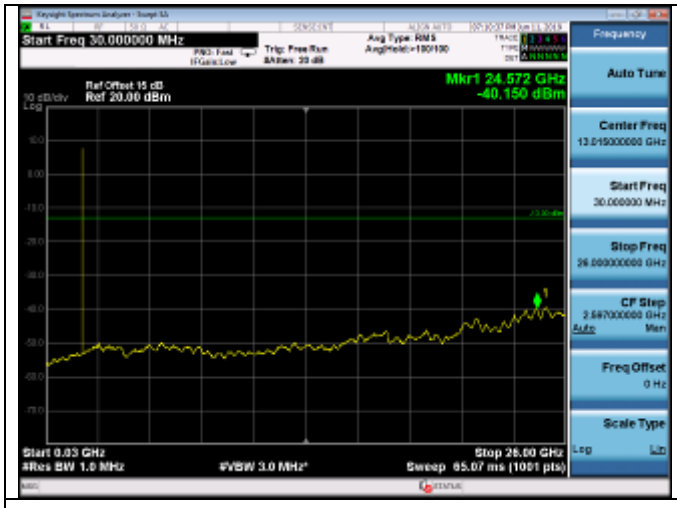
TEST RESULTS

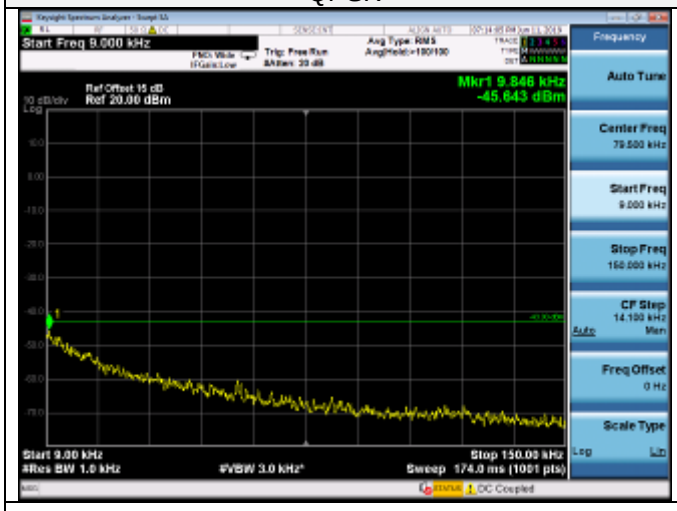
Remark:

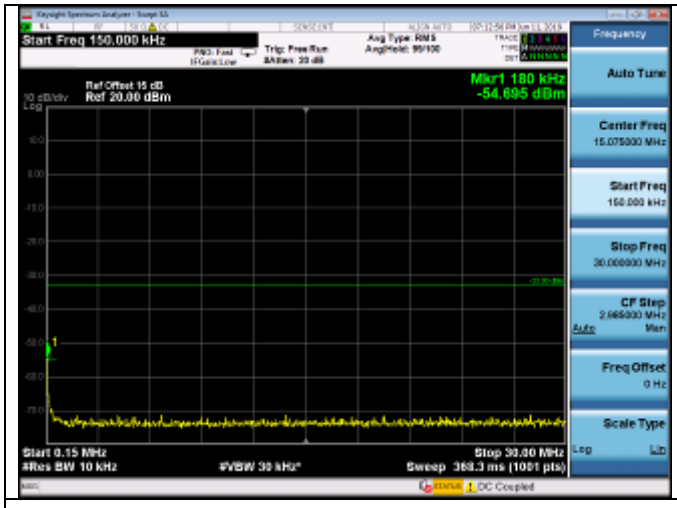
We were tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 2; recorded worst case for each Channel Bandwidth of LTE FDD Band 2.

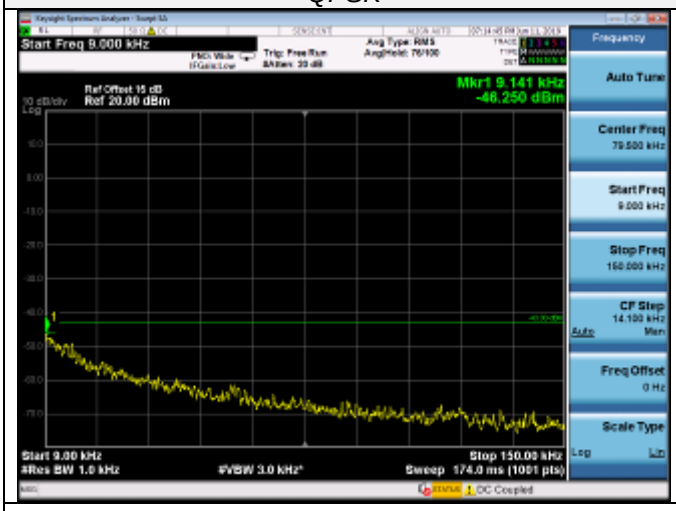
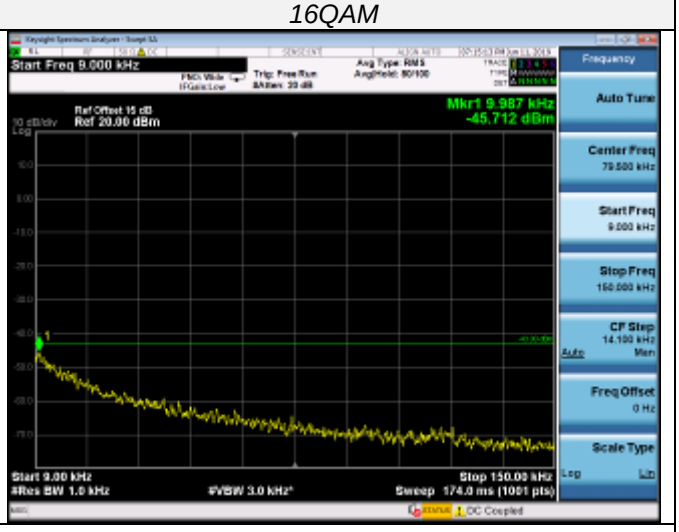
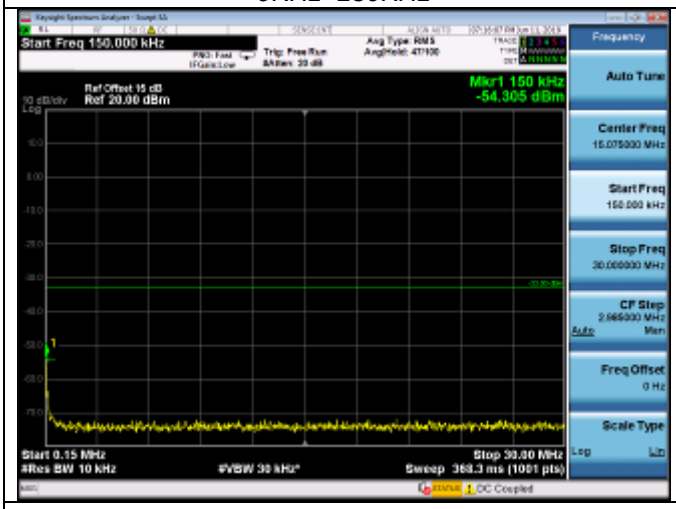
Conducted Measurement:

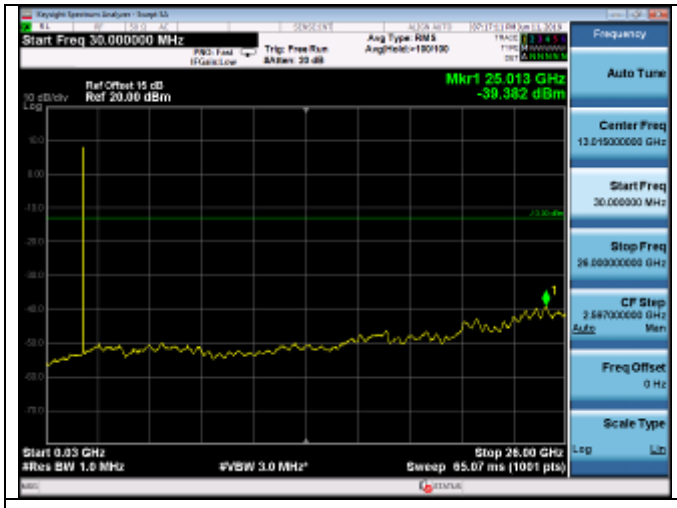
LTE FDD Band 2-1.4MHz Channel Bandwidth	
Low Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*
	
150KHz~30MHz	*150KHz~30MHz*

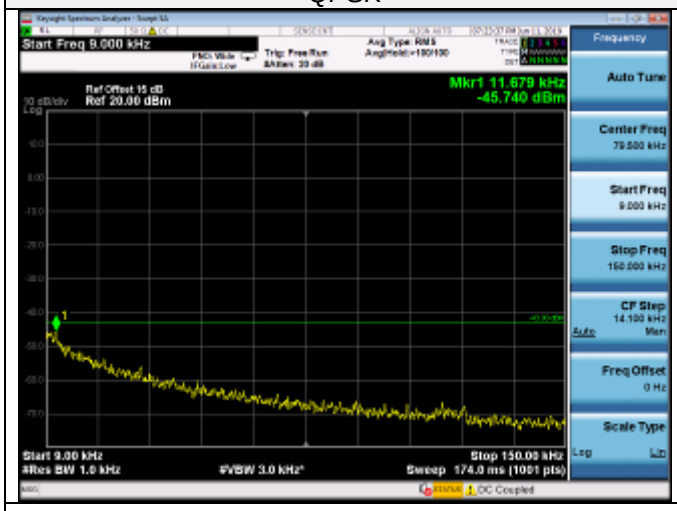
	
30MHz~26.5GHz	*30MHz~26.5GHz*
1RB#0	*1RB#0*

LTE FDD Band 2-1.4MHz Channel Bandwidth	
Middle Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*

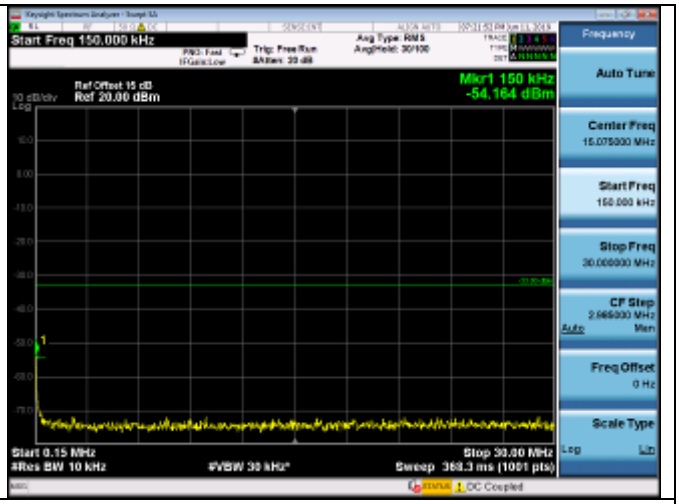
	
150KHz~30MHz	*150KHz~30MHz*
30MHz~26.5GHz	*30MHz~26.5GHz*
1RB#0	*1RB#0*

LTE FDD Band 2-1.4MHz Channel Bandwidth	
High Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*
	
150KHz~30MHz	*150KHz~30MHz*

	
30MHz~26.5GHz	*30MHz~26.5GHz*
1RB#0	*1RB#0*

LTE FDD Band 2-3MHz Channel Bandwidth	
Low Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*

150KHz~30MHz



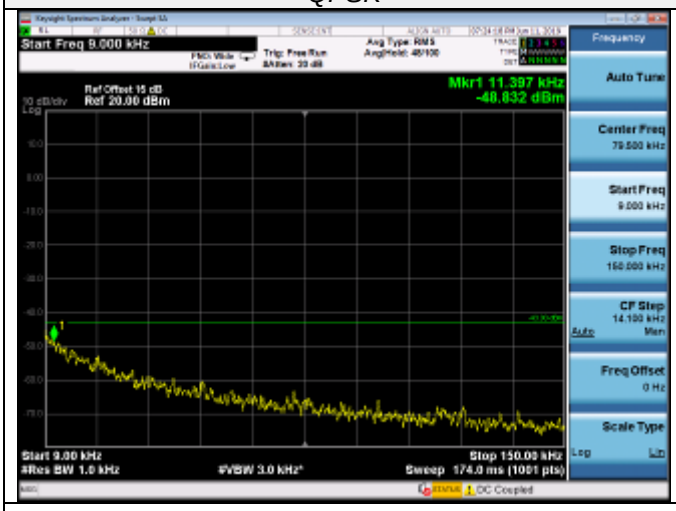
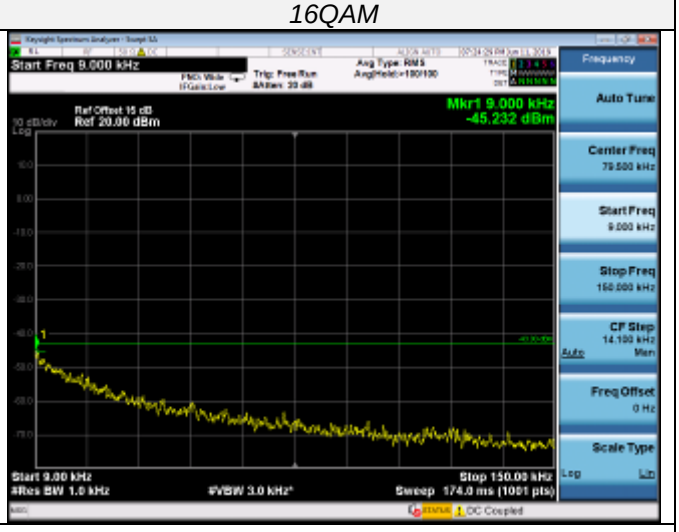
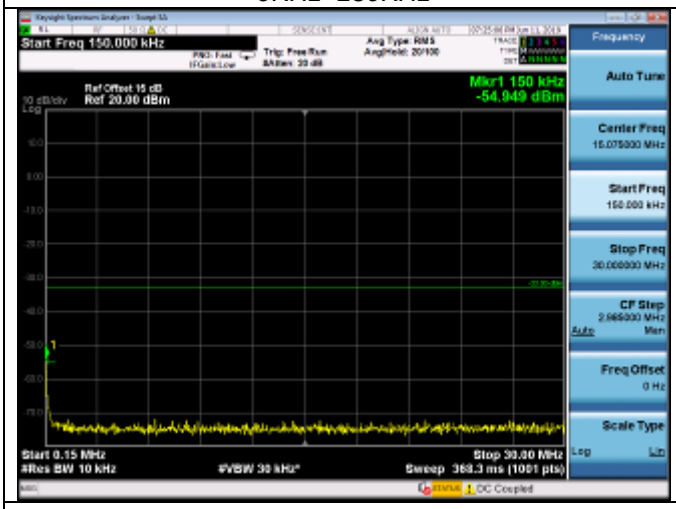
150KHz~30MHz

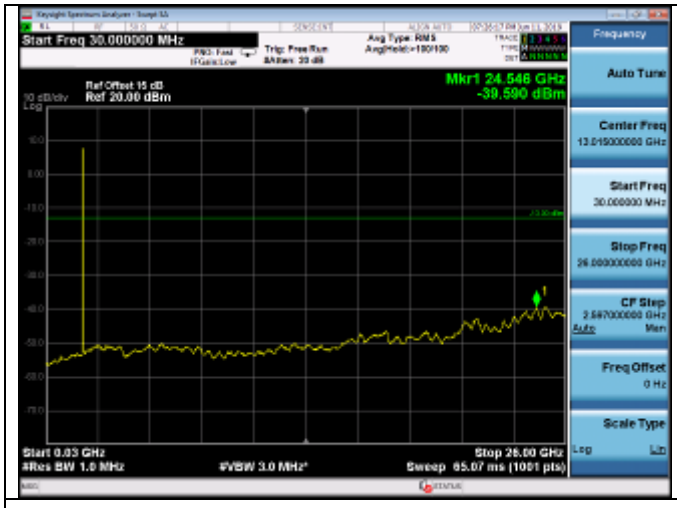
30MHz~26.5GHz

30MHz~26.5GHz

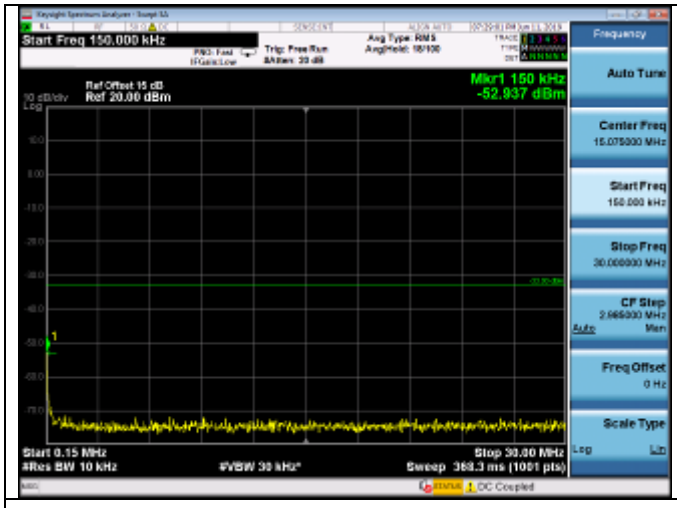
1RB#0

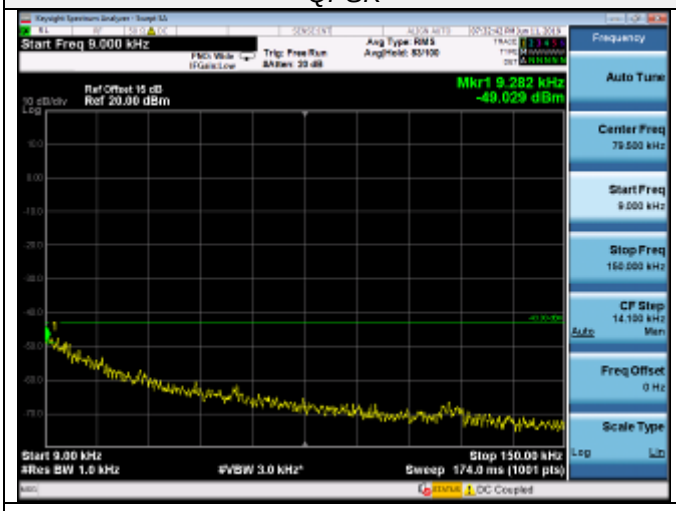
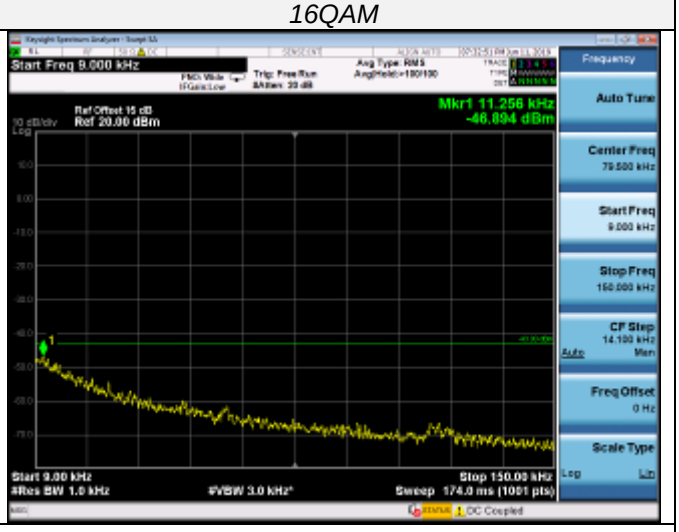
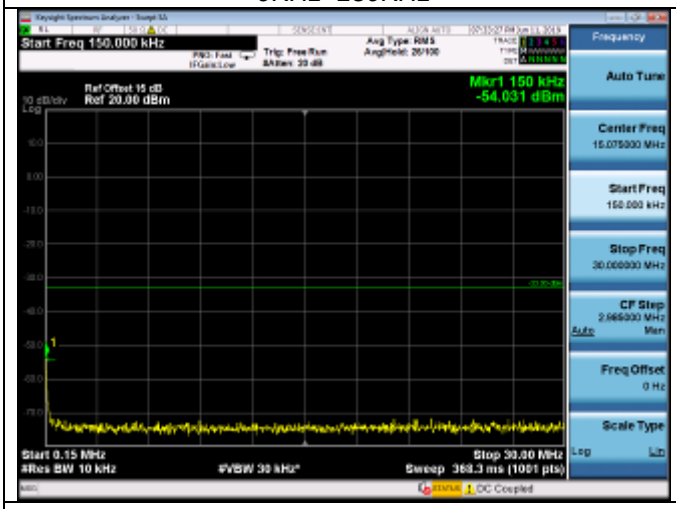
1RB#0

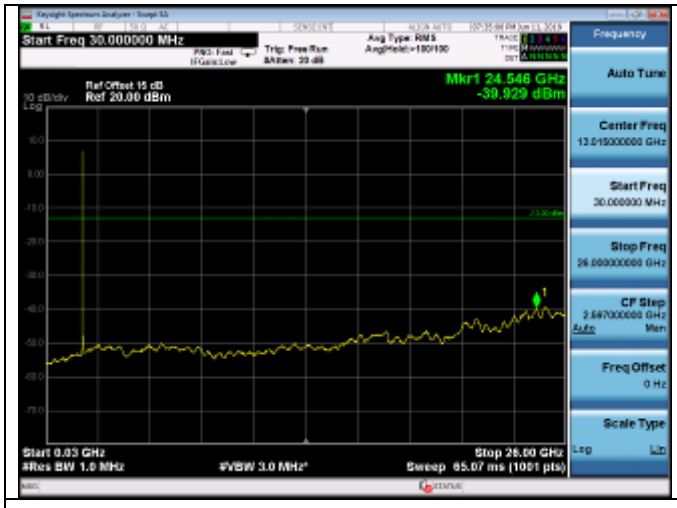
LTE FDD Band 2-3MHz Channel Bandwidth	
Middle Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*
	
150KHz~30MHz	*150KHz~30MHz*

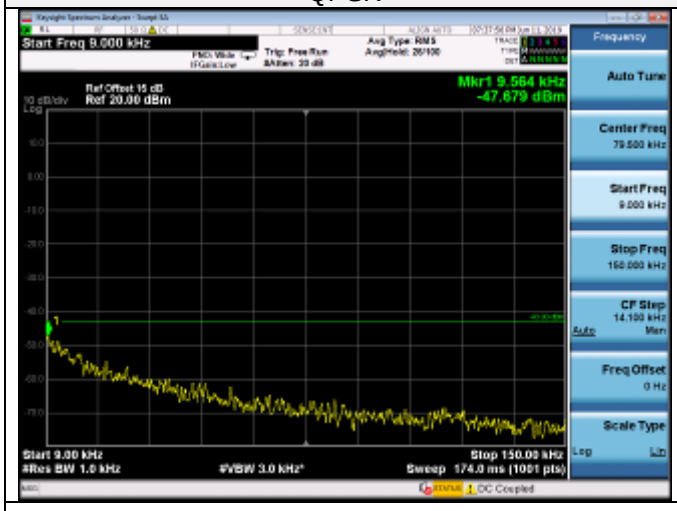
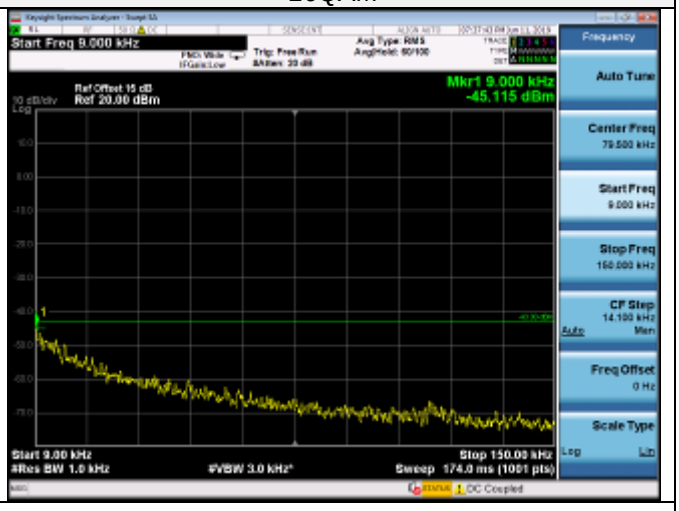
	
30MHz~26.5GHz	*30MHz~26.5GHz*
1RB#0	*1RB#0*

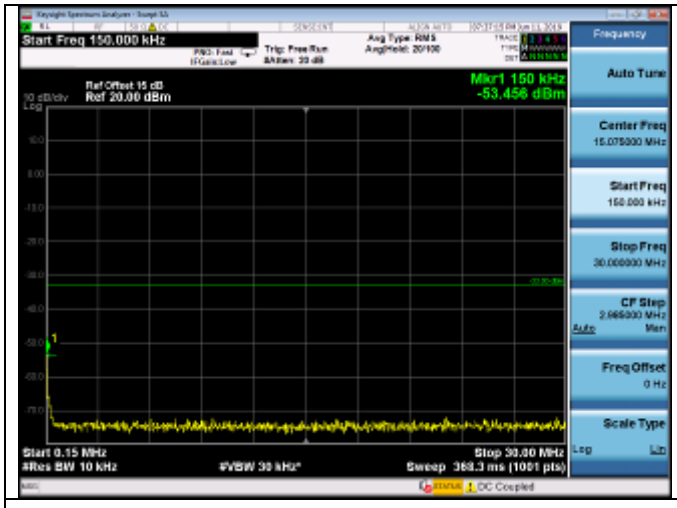
LTE FDD Band 2-3MHz Channel Bandwidth	
High Channel	
QPSK	*16QAM*
9KHz~150KHz	*9KHz~150KHz*

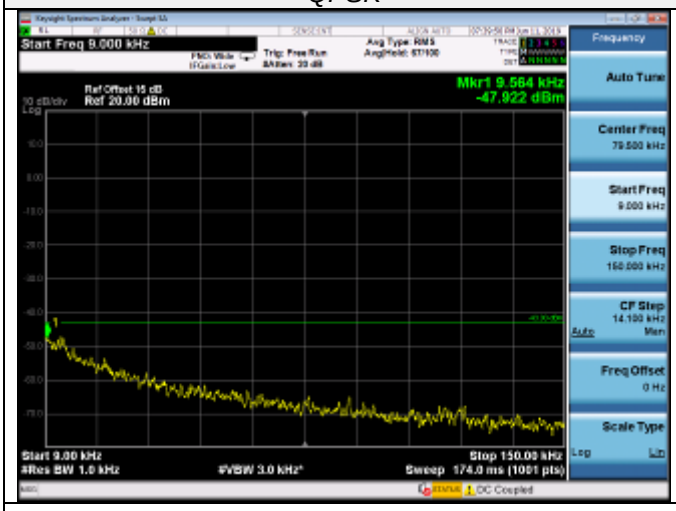
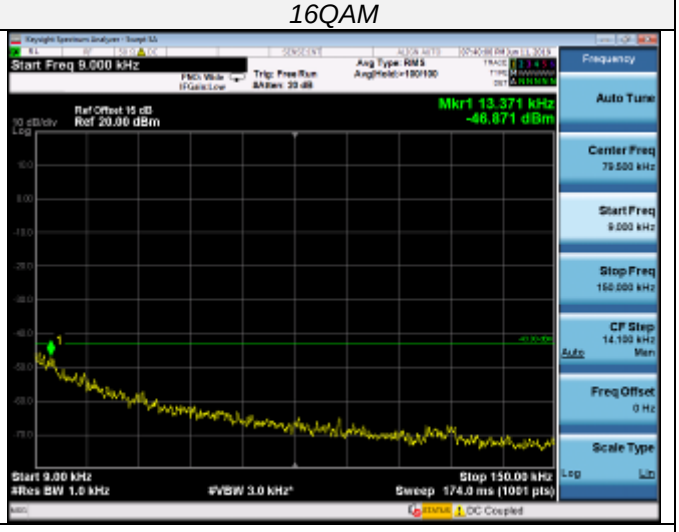
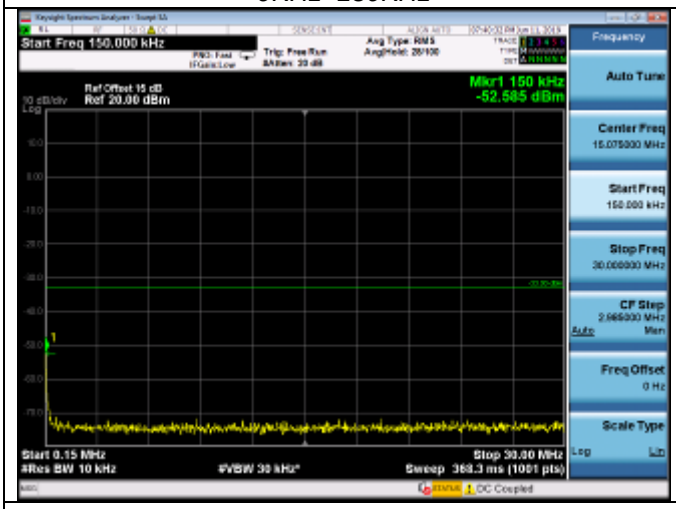
	
150KHz~30MHz	*150KHz~30MHz*
30MHz~26.5GHz	*30MHz~26.5GHz*
1RB#0	*1RB#0*

LTE FDD Band 2-5MHz Channel Bandwidth	
Low Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*
	
150KHz~30MHz	*150KHz~30MHz*

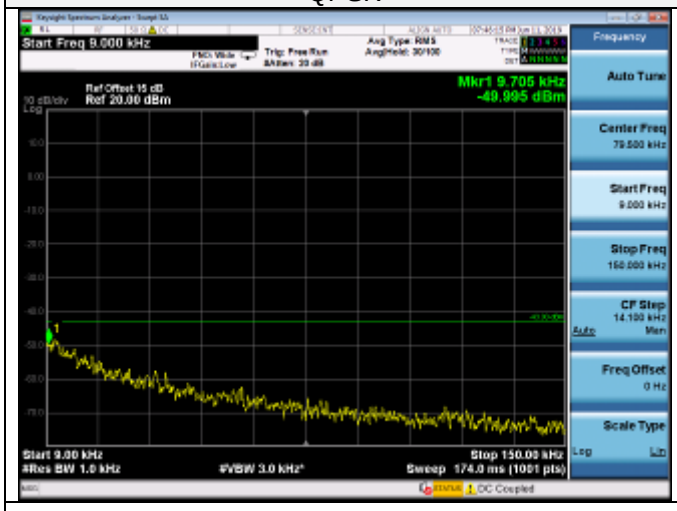
	
30MHz~26.5GHz	*30MHz~26.5GHz*
1RB#0	*1RB#0*

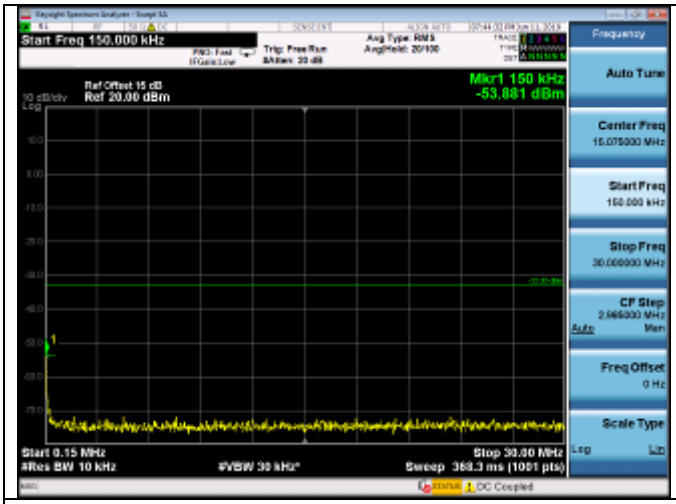
LTE FDD Band 2-5MHz Channel Bandwidth	
Middle Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*

	
150KHz~30MHz	*150KHz~30MHz*
30MHz~26.5GHz	*30MHz~26.5GHz*
1RB#0	*1RB#0*

LTE FDD Band 2-5MHz Channel Bandwidth	
High Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*
	
150KHz~30MHz	*150KHz~30MHz*

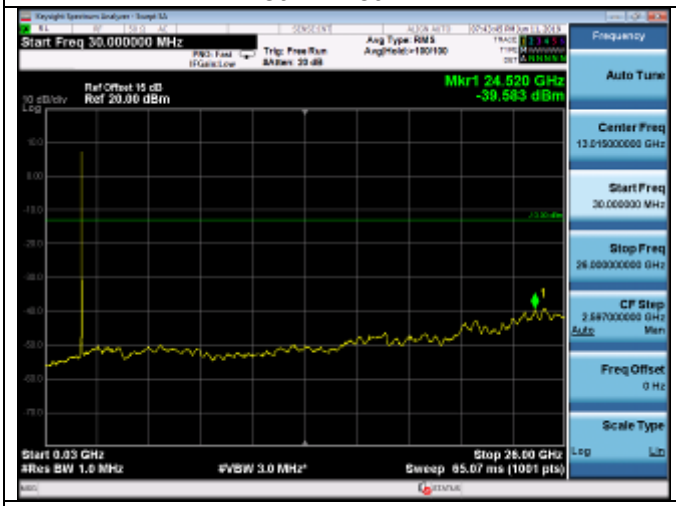
30MHz~26.5GHz	*30MHz~26.5GHz*
1RB#0	*1RB#0*

LTE FDD Band 2-10MHz Channel Bandwidth	
Low Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*



150KHz~30MHz

150KHz~30MHz

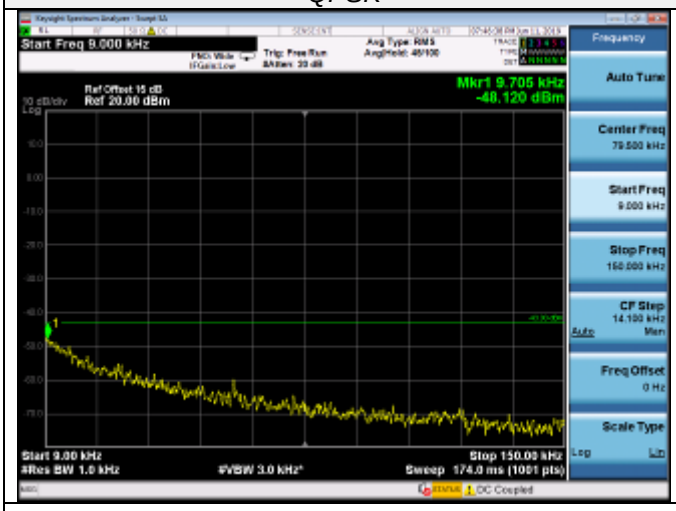
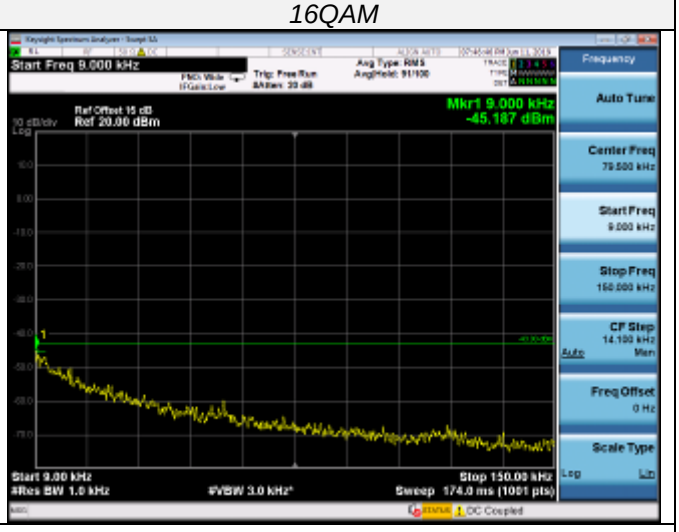
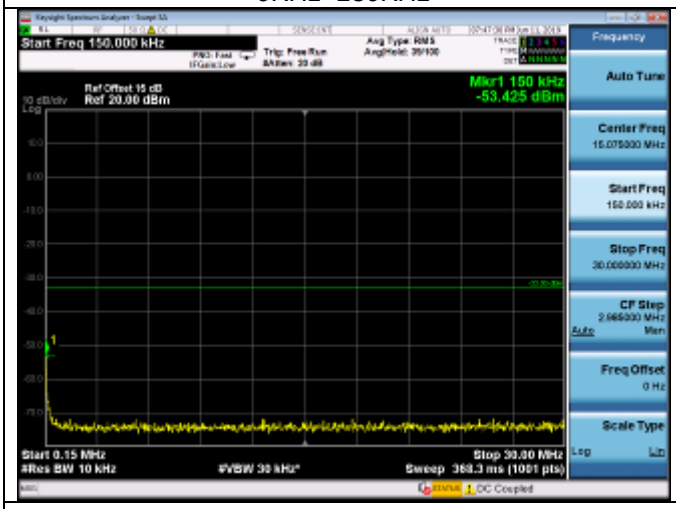


30MHz~26.5GHz

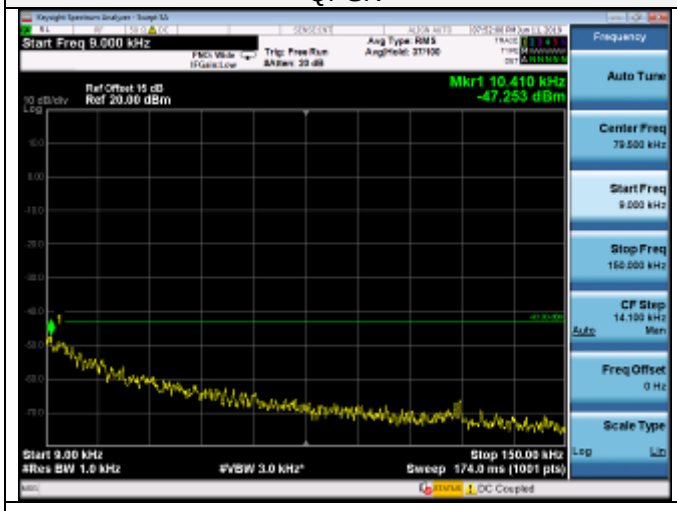
30MHz~26.5GHz

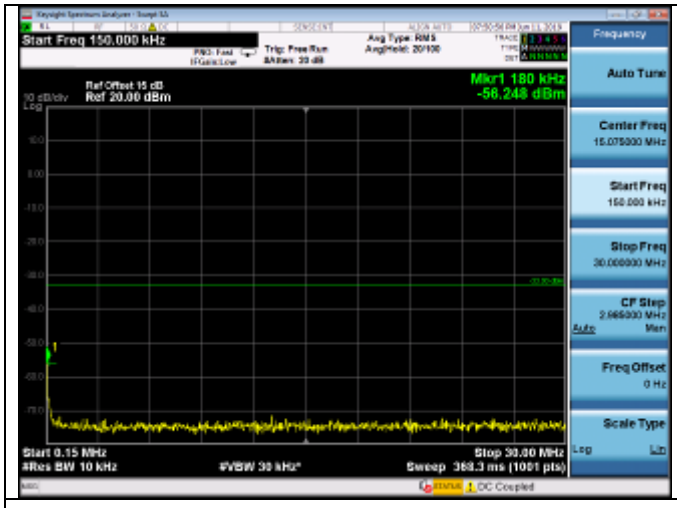
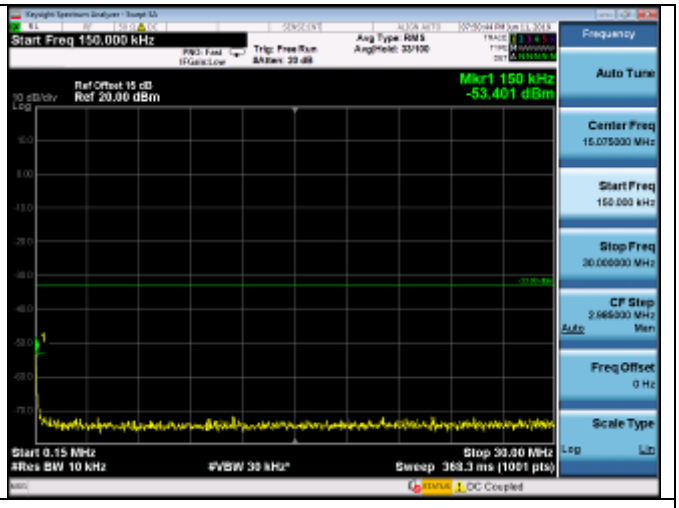
1RB#0

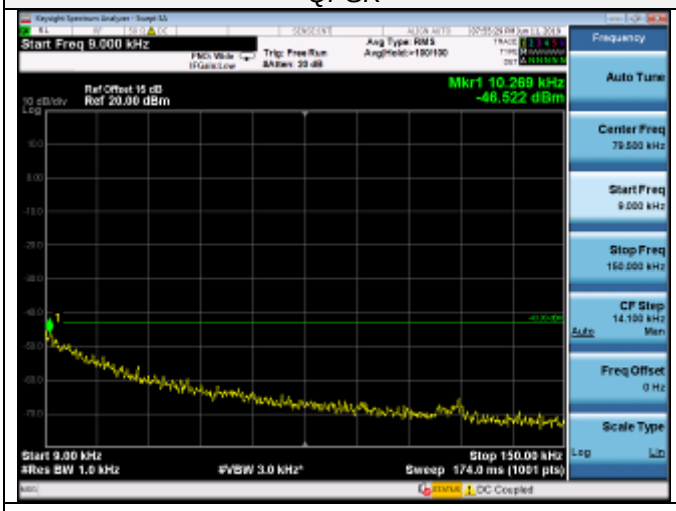
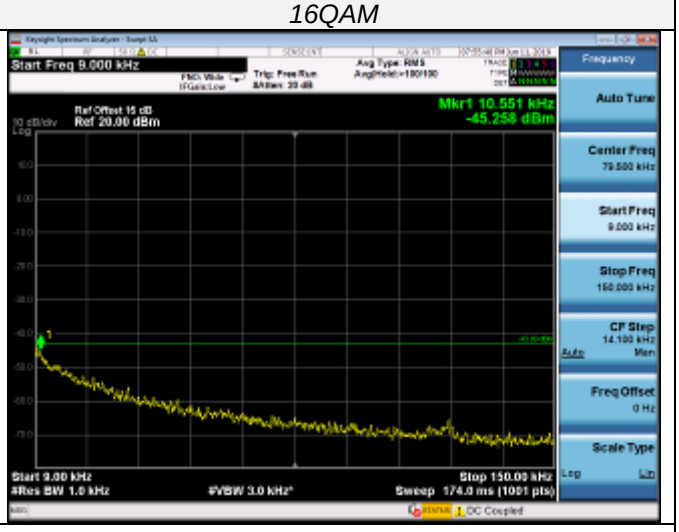
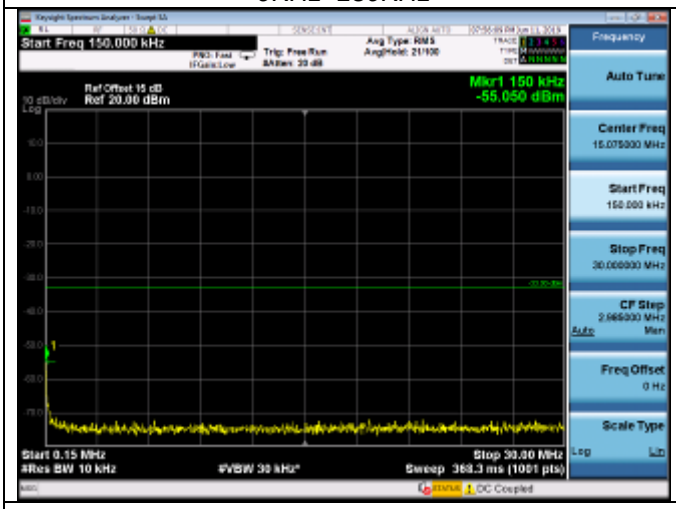
1RB#0

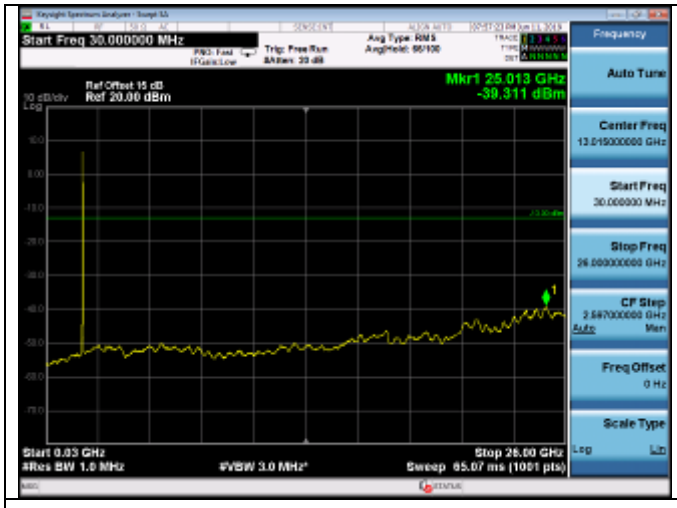
LTE FDD Band 2-10MHz Channel Bandwidth	
Middle Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*
	
150KHz~30MHz	*150KHz~30MHz*

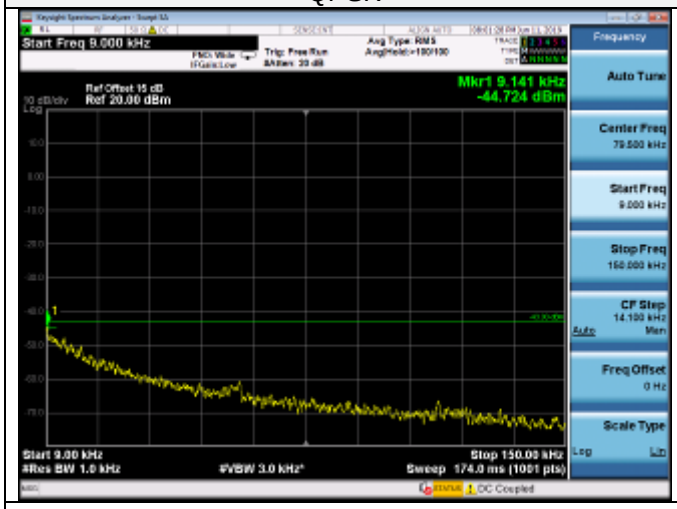
30MHz~26.5GHz	*30MHz~26.5GHz*
1RB#0	*1RB#0*

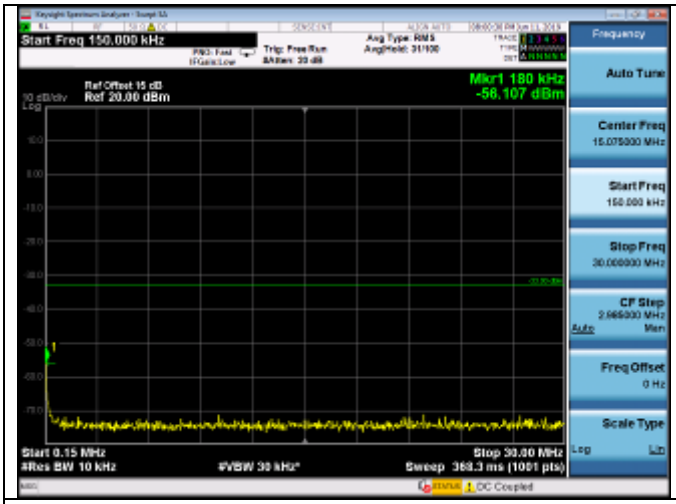
LTE FDD Band 2-10MHz Channel Bandwidth	
High Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*

	
150KHz~30MHz	*150KHz~30MHz*
30MHz~26.5GHz	*30MHz~26.5GHz*
1RB#0	*1RB#0*

LTE FDD Band 2-15MHz Channel Bandwidth	
Low Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*
	
150KHz~30MHz	*150KHz~30MHz*

	
30MHz~26.5GHz	*30MHz~26.5GHz*
1RB#0	*1RB#0*

LTE FDD Band 2-15MHz Channel Bandwidth	
Middle Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*



150KHz~30MHz

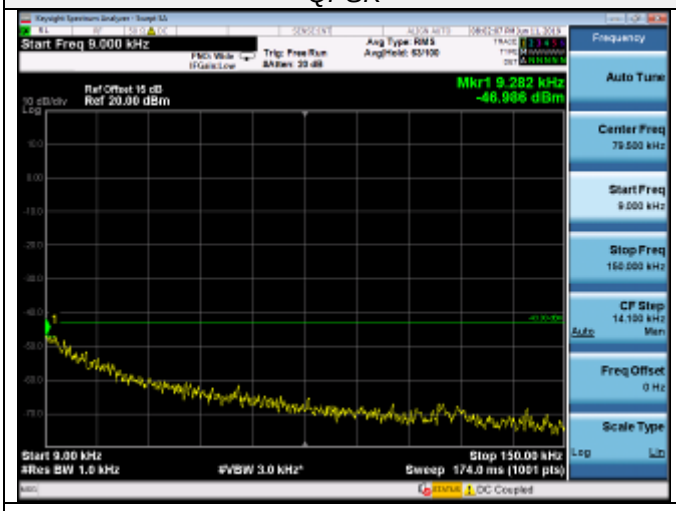
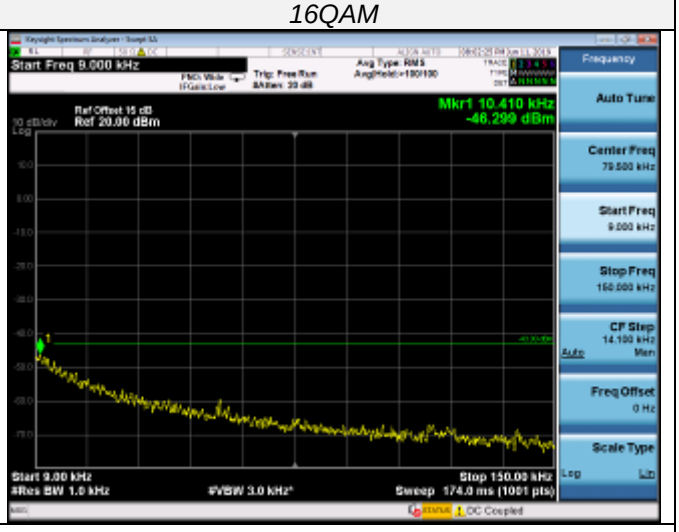
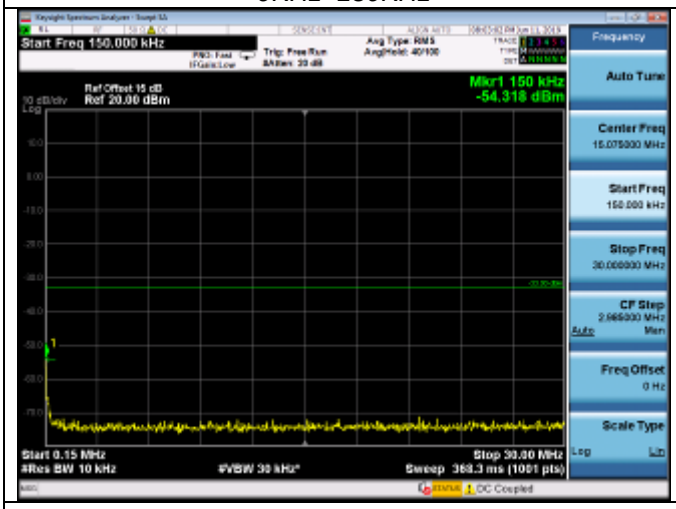
150KHz~30MHz

30MHz~26.5GHz

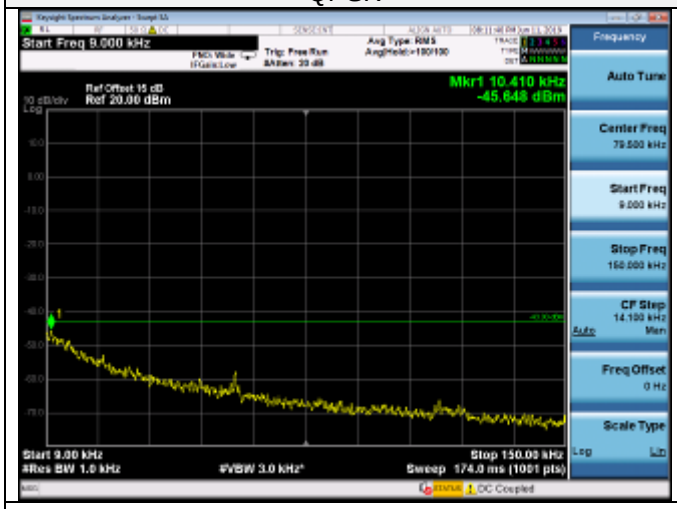
30MHz~26.5GHz

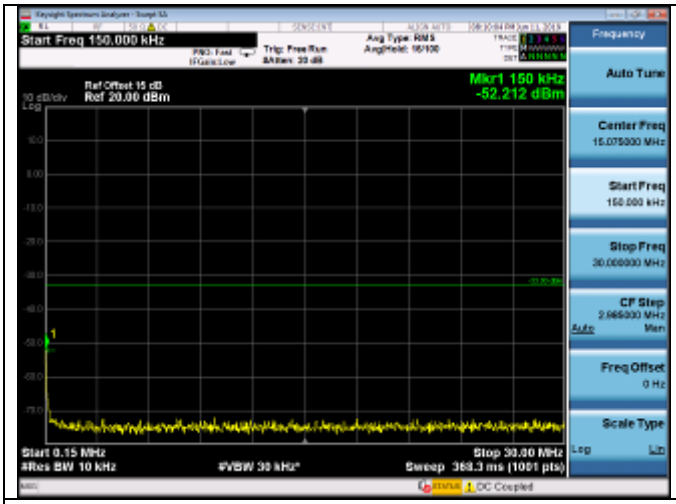
1RB#0

1RB#0

LTE FDD Band 2-15MHz Channel Bandwidth	
High Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*
	
150KHz~30MHz	*150KHz~30MHz*

30MHz~26.5GHz	*30MHz~26.5GHz*
1RB#0	*1RB#0*

LTE FDD Band 2-20MHz Channel Bandwidth	
Low Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*



150KHz~30MHz

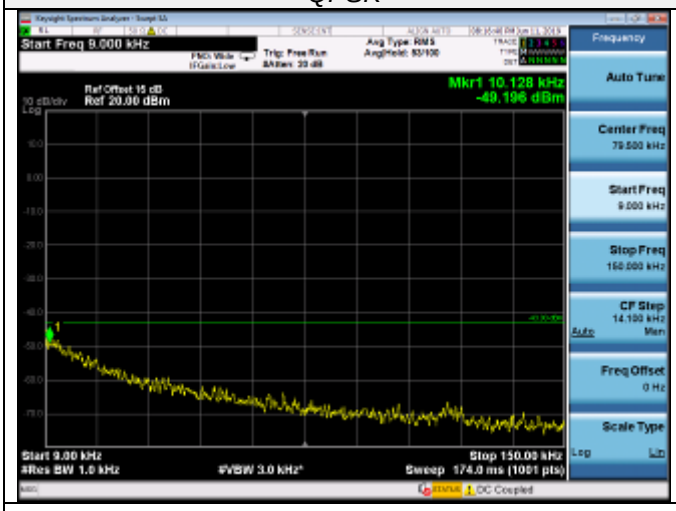
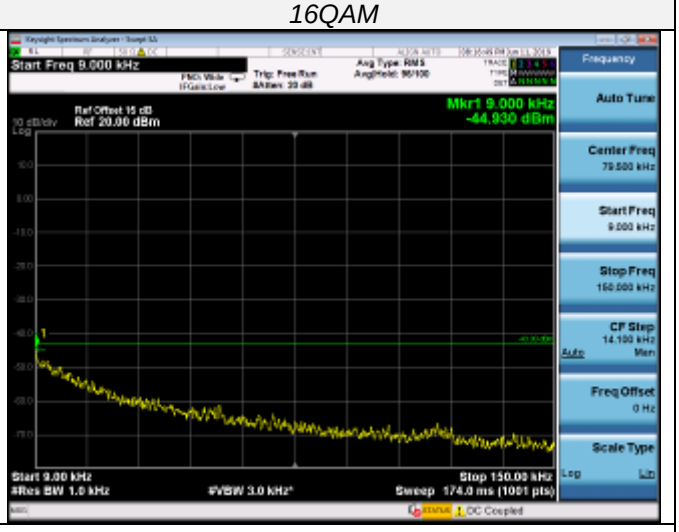
150KHz~30MHz

30MHz~26.5GHz

30MHz~26.5GHz

1RB#0

1RB#0

LTE FDD Band 2-20MHz Channel Bandwidth	
Middle Channel	
QPSK	*16QAM*
	
9KHz~150KHz	*9KHz~150KHz*
150KHz~30MHz	*150KHz~30MHz*

30MHz~26.5GHz	*30MHz~26.5GHz*
1RB#0	*1RB#0*

LTE FDD Band 2-20MHz Channel Bandwidth	
High Channel	
QPSK	*16QAM*
9KHz~150KHz	*9KHz~150KHz*

150KHz~30MHz

150KHz~30MHz

30MHz~26.5GHz

30MHz~26.5GHz

1RB#0

1RB#0

Radiated Measurement:

Remark:

1. *We were tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 2; recorded worst case for each Channel Bandwidth of LTE FDD Band 2 @ QPSK*
2. *EIRP=P_{Mea}(dBm)-P_{cl}(dB) +G_a(dBi)*
3. *We were not recorded other points as values lower than limits.*
4. *Margin = Limit - EIRP*

LTE FDD Band 2_Channel Bandwidth 1.4MHz_QPSK_ Low Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3701.4	-39.34	4.25	3.00	12.34	-31.25	-13.00	18.25	H
5552.1	-42.69	4.97	3.00	13.52	-34.14	-13.00	21.14	H
3701.4	-38.75	4.25	3.00	12.34	-30.66	-13.00	17.66	V
5552.1	-41.83	4.97	3.00	13.52	-33.28	-13.00	20.28	V

LTE FDD Band 2_Channel Bandwidth 1.4MHz_QPSK_ Middle Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3760.0	-39.52	4.38	3.00	12.34	-31.56	-13.00	18.56	H
5640.0	-43.35	5.01	3.00	13.58	-34.78	-13.00	21.78	H
3760.0	-38.50	4.38	3.00	12.34	-30.54	-13.00	17.54	V
5640.0	-42.11	5.01	3.00	13.58	-33.54	-13.00	20.54	V

LTE FDD Band 2_Channel Bandwidth 1.4MHz_QPSK_ High Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3806.6	-40.48	4.49	3.00	12.45	-32.52	-13.00	19.52	H
5709.9	-43.81	5.26	3.00	13.66	-35.41	-13.00	22.41	H
3806.6	-38.41	4.49	3.00	12.45	-30.45	-13.00	17.45	V
5709.9	-41.66	5.26	3.00	13.66	-33.26	-13.00	20.26	V

LTE FDD Band 2_Channel Bandwidth 3MHz_QPSK_ Low Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3703.0	-39.96	4.25	3.00	12.34	-31.87	-13.00	18.87	H
5554.5	-44.00	4.97	3.00	13.52	-35.45	-13.00	22.45	H
3703.0	-37.34	4.25	3.00	12.34	-29.25	-13.00	16.25	V
5554.5	-43.03	4.97	3.00	13.52	-34.48	-13.00	21.48	V

LTE FDD Band 2_Channel Bandwidth 3MHz_QPSK_ Middle Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3760.0	-39.94	4.38	3.00	12.34	-31.98	-13.00	18.98	H
5640.0	-43.09	5.01	3.00	13.58	-34.52	-13.00	21.52	H
3760.0	-38.75	4.38	3.00	12.34	-30.79	-13.00	17.79	V
5640.0	-42.25	5.01	3.00	13.58	-33.68	-13.00	20.68	V

LTE FDD Band 2_Channel Bandwidth 3MHz_QPSK_ High Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3817.0	-39.40	4.49	3.00	12.45	-31.44	-13.00	18.44	H
5725.5	-43.81	5.26	3.00	13.66	-35.41	-13.00	22.41	H
3817.0	-37.24	4.49	3.00	12.45	-29.28	-13.00	16.28	V
5725.5	-42.94	5.26	3.00	13.66	-34.54	-13.00	21.54	V

LTE FDD Band 2_Channel Bandwidth 5MHz_QPSK_ Low Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3705.0	-39.98	4.25	3.00	12.34	-31.89	-13.00	18.89	H
5557.5	-44.15	4.97	3.00	13.52	-35.60	-13.00	22.60	H
3705.0	-38.96	4.25	3.00	12.34	-30.87	-13.00	17.87	V
5557.5	-42.07	4.97	3.00	13.52	-33.52	-13.00	20.52	V

LTE FDD Band 2_Channel Bandwidth 5MHz_QPSK_ Middle Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3760.0	-39.45	4.38	3.00	12.34	-31.49	-13.00	18.49	H
5640.0	-44.04	5.01	3.00	13.58	-35.47	-13.00	22.47	H
3760.0	-37.95	4.38	3.00	12.34	-29.99	-13.00	16.99	V
5640.0	-42.77	5.01	3.00	13.58	-34.20	-13.00	21.20	V

LTE FDD Band 2_Channel Bandwidth 5MHz_QPSK_ High Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3815.0	-39.47	4.49	3.00	12.45	-31.51	-13.00	18.51	H
5722.5	-43.14	5.26	3.00	13.66	-34.74	-13.00	21.74	H
3815.0	-38.22	4.49	3.00	12.45	-30.26	-13.00	17.26	V
5722.5	-41.28	5.26	3.00	13.66	-32.88	-13.00	19.88	V

LTE FDD Band 2_Channel Bandwidth 10MHz_QPSK_ Low Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3710.0	-39.50	4.25	3.00	12.34	-31.41	-13.00	18.41	H
5565.0	-43.07	4.97	3.00	13.52	-34.52	-13.00	21.52	H
3710.0	-39.05	4.25	3.00	12.34	-30.96	-13.00	17.96	V
5565.0	-41.39	4.97	3.00	13.52	-32.84	-13.00	19.84	V

LTE FDD Band 2_Channel Bandwidth 10MHz_QPSK_ Middle Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3760.0	-39.50	4.38	3.00	12.34	-31.54	-13.00	18.54	H
5640.0	-43.67	5.01	3.00	13.58	-35.10	-13.00	22.10	H
3760.0	-37.54	4.38	3.00	12.34	-29.58	-13.00	16.58	V
5640.0	-42.77	5.01	3.00	13.58	-34.20	-13.00	21.20	V

LTE FDD Band 2_Channel Bandwidth 10MHz_QPSK_ High Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3810.0	-40.21	4.49	3.00	12.45	-32.25	-13.00	19.25	H
5715.0	-42.64	5.26	3.00	13.66	-34.24	-13.00	21.24	H
3810.0	-38.74	4.49	3.00	12.45	-30.78	-13.00	17.78	V
5715.0	-41.81	5.26	3.00	13.66	-33.41	-13.00	20.41	V

LTE FDD Band 2_Channel Bandwidth 15MHz_QPSK_ Low Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3715.0	-39.72	4.25	3.00	12.34	-31.63	-13.00	18.63	H
5572.5	-43.42	4.97	3.00	13.52	-34.87	-13.00	21.87	H
3715.0	-38.50	4.25	3.00	12.34	-30.41	-13.00	17.41	V
5572.5	-40.75	4.97	3.00	13.52	-32.20	-13.00	19.20	V

LTE FDD Band 2_Channel Bandwidth 15MHz_QPSK_ Middle Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3760.0	-39.32	4.38	3.00	12.34	-31.36	-13.00	18.36	H
5640.0	-42.82	5.01	3.00	13.58	-34.25	-13.00	21.25	H
3760.0	-38.85	4.38	3.00	12.34	-30.89	-13.00	17.89	V
5640.0	-42.01	5.01	3.00	13.58	-33.44	-13.00	20.44	V

LTE FDD Band 2_Channel Bandwidth 15MHz_QPSK_ High Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3805.0	-39.86	4.49	3.00	12.45	-31.90	-13.00	18.90	H
5707.5	-43.85	5.26	3.00	13.66	-35.45	-13.00	22.45	H
3805.0	-38.29	4.49	3.00	12.45	-30.33	-13.00	17.33	V
5707.5	-42.90	5.26	3.00	13.66	-34.50	-13.00	21.50	V

LTE FDD Band 2_Channel Bandwidth 20MHz_QPSK_ Low Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3715.0	-39.44	4.25	3.00	12.34	-31.35	-13.00	18.35	H
5572.5	-42.82	4.97	3.00	13.52	-34.27	-13.00	21.27	H
3715.0	-38.98	4.25	3.00	12.34	-30.89	-13.00	17.89	V
5572.5	-40.96	4.97	3.00	13.52	-32.41	-13.00	19.41	V

LTE FDD Band 2_Channel Bandwidth 20MHz_QPSK_ Middle Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3720.0	-39.41	4.38	3.00	12.34	-31.45	-13.00	18.45	H
5580.0	-44.07	5.01	3.00	13.58	-35.50	-13.00	22.50	H
3720.0	-38.70	4.38	3.00	12.34	-30.74	-13.00	17.74	V
5580.0	-41.89	5.01	3.00	13.58	-33.32	-13.00	20.32	V

LTE FDD Band 2_Channel Bandwidth 20MHz_QPSK_ High Channel

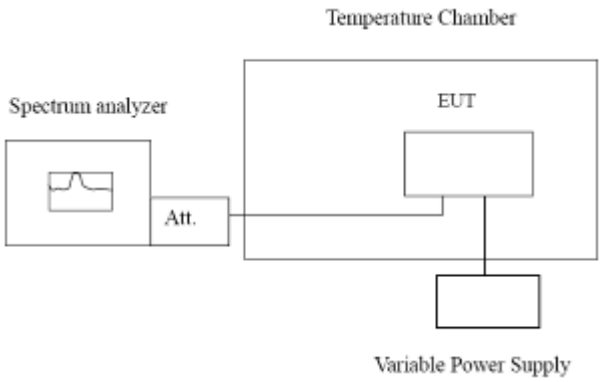
Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dBi)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3800.0	-39.40	4.49	3.00	12.45	-31.44	-13.00	18.44	H
5700.0	-42.98	5.26	3.00	13.66	-34.58	-13.00	21.58	H
3800.0	-38.51	4.49	3.00	12.45	-30.55	-13.00	17.55	V
5700.0	-42.05	5.26	3.00	13.66	-33.65	-13.00	20.65	V

4.6 Frequency Stability under Temperature & Voltage Variations

LIMIT

According to §24.235, §2.1055 requirement, the frequency stability shall be sufficient to ensure that the fundamental emissions stay within the authorized bands of operation and should not exceed 2.5ppm.

TEST CONFIGURATION



TEST PROCEDURE

The EUT was setup according to EIA/TIA 603E

Frequency Stability under Temperature Variations:

In order to measure the carrier frequency under the condition of AFC lock, it is necessary to make measurements with the EUT in a “call mode”. This is accomplished with the use of R&S CMW500 DIGITAL RADIO COMMUNICATION TESTER.

1. Measure the carrier frequency at room temperature.
2. Subject the EUT to overnight soak at -20℃.
3. With the EUT, powered via nominal voltage, connected to the CMW500 and in a simulated call on middle channel for LTE band 2, measure the carrier frequency. These measurements should be made within 2 minutes of Powering up the EUT, to prevent significant self-warming.
4. Repeat the above measurements at 10℃ increments from -20℃ to +50℃. Allow at least 1.5 hours at each temperature, unpowered, before making measurements.
5. Re-measure carrier frequency at room temperature with nominal voltage. Vary supply voltage from minimum voltage to maximum voltage, in 0.1Volt increments re-measuring carrier frequency at each voltage. Pause at nominal voltage for 1.5 hours unpowered, to allow any self-heating to stabilize, before continuing.
6. Subject the EUT to overnight soak at +50℃.
7. With the EUT, powered via nominal voltage, connected to the CMW500 and in a simulated call on the centre channel, measure the carrier frequency. These measurements should be made within 2 minutes of Powering up the EUT, to prevent significant self-warming.
8. Repeat the above measurements at 10 ℃ increments from +50℃ to -20℃. Allow at least 1.5 hours at each temperature, unpowered, before making measurements

9. At all temperature levels hold the temperature to +/- 0.5℃ during the measurement procedure.

Frequency Stability under Voltage Variations:

Set chamber temperature to 20℃. Use a variable AC power supply / DC power source to power the EUT and set the voltage to rated voltage. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and recorded the frequency.

Reduce the input voltage to specify extreme voltage variation (±15%) and endpoint, record the maximum frequency change.

TEST RESULTS

Remark:

We tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 2; recorded worst case LTE Band 2, 1.4MHz bandwidth (worst case of all bandwidths)

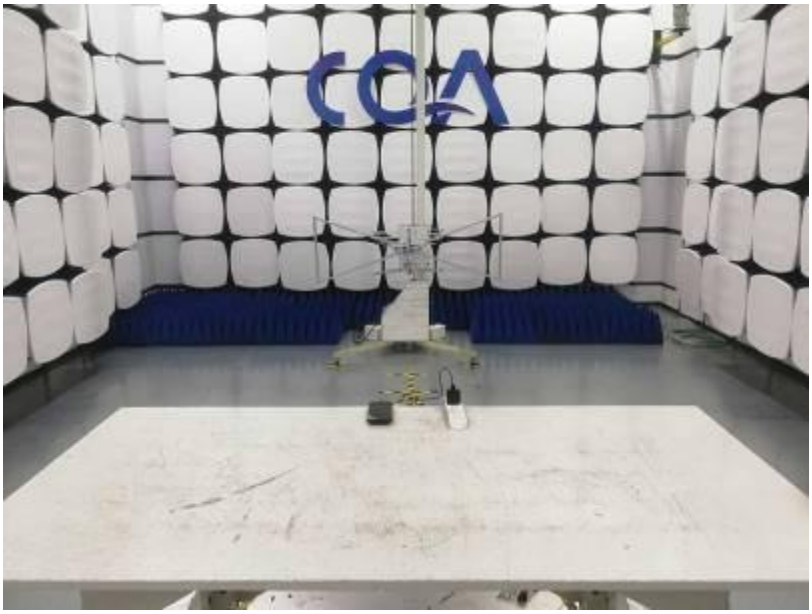
Frequency Error vs Voltage

Voltage (V)	Frequency error (Hz)		Frequency error (ppm)		Limit (ppm)
	QPSK	16QAM	QPSK	16QAM	
3.5	-2.77	-3.04	-0.00147	-0.00162	2.50
4.2	0.41	2.07	0.00022	0.00110	2.50
4.5	9.69	7.22	0.00515	0.00384	2.50

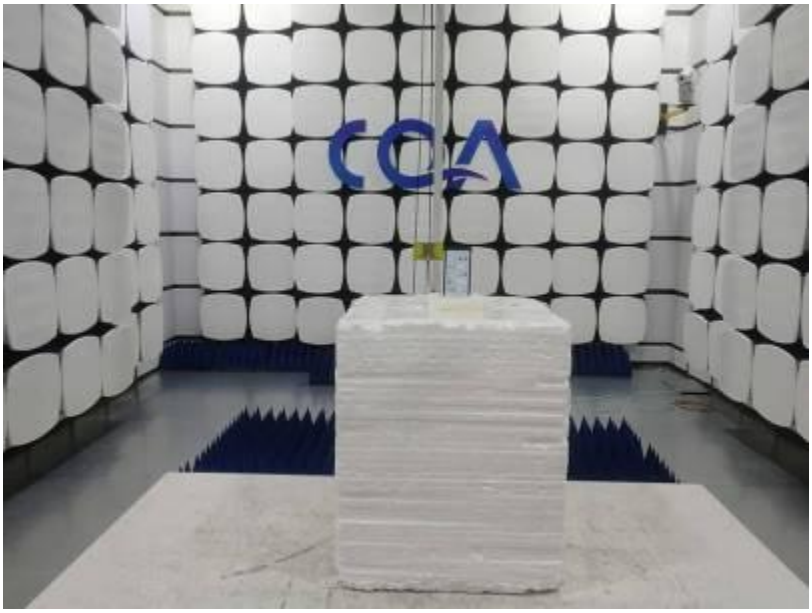
Frequency Error vs Temperature

Temperature (℃)	Frequency error (Hz)		Frequency error (ppm)		Limit (ppm)
	QPSK	16QAM	QPSK	16QAM	
-20°	-0.63	-7.57	-0.00034	-0.00403	2.50
-10°	-4.10	0.57	-0.00218	0.00030	2.50
0°	3.29	8.17	0.00175	0.00435	2.50
10°	-9.34	-6.06	-0.00497	-0.00322	2.50
20°	-6.94	-9.90	-0.00369	-0.00527	2.50
30°	-8.17	2.84	-0.00435	0.00151	2.50
40°	-3.93	0.81	-0.00209	0.00043	2.50
50°	8.16	3.01	0.00434	0.00160	2.50

5 Test Setup Photos of the EUT



30MHz~1GHz



Above 1GHz

6 Photos of the EUT

Please refer to the report No: CQASZ20190500014EX-01

**********End of Report**********